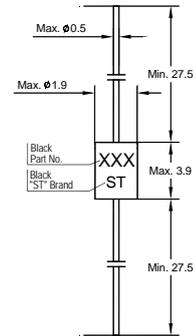# DB3, DB4, DC34

Silicon Bidirectional Trigger Diodes

These diacs are intended for use in thyristor phase control, circuits for lamp-dimming, universal-motor speed controls, and heat controls.

Max. Ø0.5

Max. Ø1.9

Min. 27.5

Black Part No.
Black "ST" Brand

XXX
ST

Max. 3.9

Min. 27.5

Glass Case DO-35
Dimensions in mm

Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Power Dissipation (T_a = 65 °C)	P_{tot}	150	mW
Repetitive Peak On-state Current (tp = 20 µs, f = 100 Hz)	I_{TRM}	2	A
Operating Junction and Storage Temperature Range	T_j, T_{stg}	- 40 to + 125	°C

Characteristics at T_a = 25 °C

| Parameter		Symbol	Min.	Max.	Unit
Breakover Voltage at C = 22 nF, see diagram 1	DB3	V_{BO}	28	36	V
	DC34		30	38	
	DB4		35	45	
Breakover Voltage Symmetry at C = 22 nF, see diagram 1		$[|+V_{BO}|-|-V_{BO}|]$	-	3	V
Dynamic Breakover Voltage at $\Delta I = [I_{BO}$ to I_F = 10 mA]		$| \Delta V \pm |$	5	-	V
Output Voltage See diagram 2		V_O	5	-	V
Breakover Current at C = 22 nF		I_{BO}	-	50	µA
Leakage Current at V_B = 0.5 V_{BO} max		I_B	-	10	µA
Rise Time See diagram 3		t_r	-	2	µs
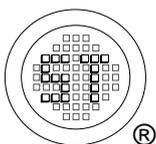
Dated : 08/08/2009
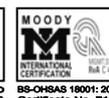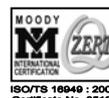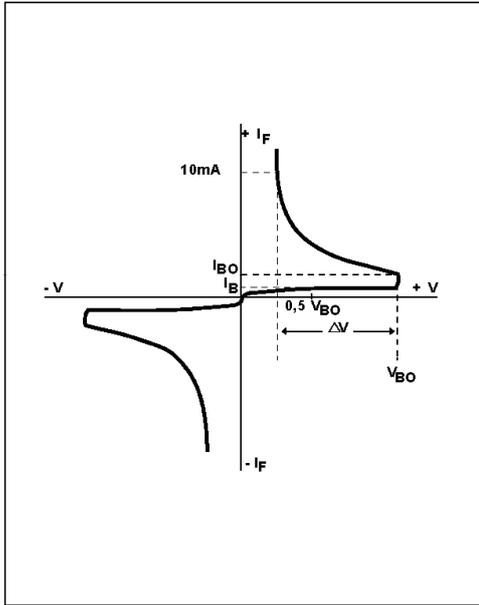
Diagram 1: Current-voltage characteristics
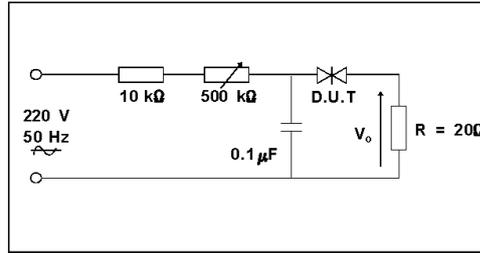

Diagram 2: Test circuit for output voltage

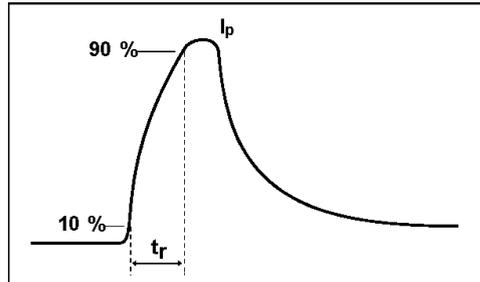Diagram 3: Test circuit see diagram 2.
Adjust R for Ip=0.5A

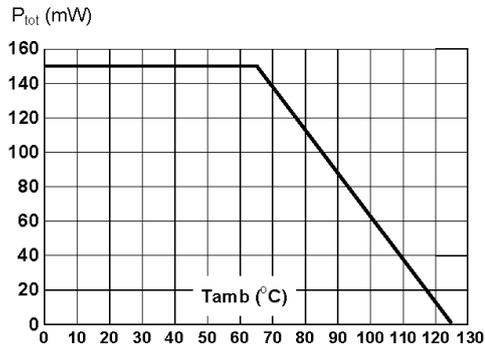Fig. 1: Power dissipation versus ambient temperature (maximum values)

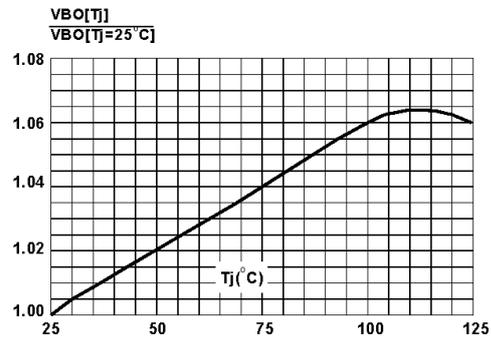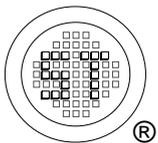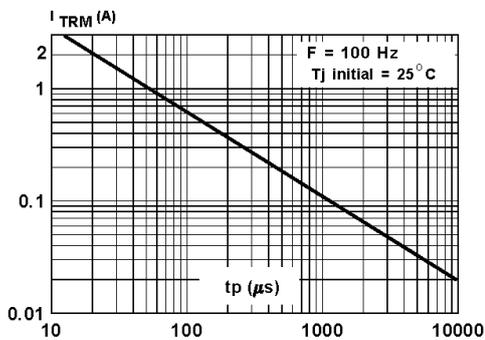Fig. 2: Relative variation of V_{BO} versus junction temperature (typical values)

Fig. 3: Peak pulse current versus pulse duration (maximum values)

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Dated : 08/08/2009